Low momentum PID at High B-field with GridPix

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Restate the Problem



- DIRC has low-p limitations:
 - Curl Up (0.45 GeV/c)
 - Kaon threshold (0.47 GeV/c)
- Rather than lower the field:
 - PID at low radius.
 - dE/dx separations huge!
 - 1.6X pi-K
 - 2.25X K-p
 - GridPIX
 - Established
 - Robust
 - Excellent tracking

Garfield Setup

25-50cm 10 cm 2 cm 25 cm 50 cm Use HUGE plates to get uniform field Limited sensitive area

- Consider r=0.5 meter
- Defines p(max) = 0.8 GeV/c
- P(list)
 - 0.2 0.4 0.6 0.8
- Z(list)
 - 2 10 25 50
- ID(list)
 - Pi, K, p
- Conditions:
 - 4*4*3 = 48 conditions
- Gas(list)
 - T2K only (for now)
- B(list)
 - 3 T only (for now)
- E(list)
 - 130 V/cm

Simple Ntuple (for now)

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- Designed to not change as studies evolve
- Ntuple: q, mass, p, theta, phi, zed, gas, B, E, track #, cluster #, x0, y0, z0, t0, xf, yf, zf, tf

ID Kinematics

Detector

Electrons

Garfield Setup (offline Analysis)



- A few simple entries into the Ntuple for code development
- Diffusion noted as sqrt(path length)
- Analysis framework getting close to producing real results...

GEANT and Fun4ALL Setup (by Sanghwa)



Preliminary Geometry in GEANT

Care required!

- Default GEANT insufficient job for ionization
- Electron-by-electron in clusters vital.

Anticipated dE/dx Resolution



Overly Simplified Momentum Resolution

• Figure of Merit:

$$\sigma_p \propto \frac{\sigma_{hit}}{\sqrt{N_{meas}}} \equiv Figure \ of \ Merit$$

- Can be compared to Silicon with detailed Monte Carlo
- Here is simple-minded estimate

• Figure of Merit(Si) =
$$\frac{\frac{20 \ \mu m}{\sqrt{12}}}{\sqrt{4}} = 2.9 \ \mu m$$

- Gas:
 - Including efficiency ~3000 electrons (minimum!) per track
 - Each suffers digitization (σ = 55 µm/sqrt(12) = 16 µm)

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- Diffusion(Length) = $25 \frac{\mu m}{\sqrt{L}} \sqrt{L}$
 - \sqrt{cm}
 - D(2cm) = 35 μm → FOM = 0.70 μm
 - D(25cm) = 125 μm → FOM = 2.3 μm
 - D(50cm) = 176 μm → FOM = 3.2 μm
 - D(100cm) = 250 μm → FOM = 4.6 μm
- Although ignoring many significant effects, initial result is on the order of the layers of silicon.

